

A case study of a metal/organic interface at the molecular level: a tip/C₆₀ contact

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In this work, we analyze theoretically a Au/C₆₀ interface based on the results obtained using DFT for a fully relaxed Au-tip/C₆₀/Au-tip geometry [1] with variable tip/tip distance, calculate the energy, forces, conductance and deformation, and discuss the organic/barrier formation at the molecular level comparing it with the full monolayer case [2]. We also analyze how this barrier formation at the molecular level can be related to the effective intrasite Coulomb interaction operating in the molecule (considered as a quantum dot). Finally, we also discuss how that Coulomb interaction allows us to obtain the transport energy gap of the molecule as a function of the tip-molecule distance.

The contact formation is analyzed by approaching each Au-tip in steps of 0.1 Å using a highly efficient MD-DFT code (FIREBALL[3]). After each step the atoms are relaxed to their corresponding minimum energy positions, excepting the atoms in the last Au-layer of both tips. We use the LDA exchange-correlation functional, and a basis set of short-range numerical atomic-like orbitals (NAOs). The electrical conductance of the system was calculated at each step of the deformation using a Keldish-Green's function approach [4], together with the first-principles tight-binding hamiltonian of the system.

We have also calculated the density of states at several steps of the tip approach and analyzed them in terms of the Unified-IDIS model [6] For each case, the LUMO and HOMO levels, the molecule Charge Neutrality Level, the Fermi energy (zero energy) and the initial metal workfunction, Φ_M , are shown. The CNL is calculated integrating the C₆₀-DOS up to charge neutrality conditions; the tip/C₆₀/tip contact reacts creating a potential, V^t , that tries to align the organic CNL and the metal workfunction. Following the IDIS-description of MO interfaces [6], we can relate the total potential difference, V^t , created between the tips and C₆₀, to the IDIS, V^{IDIS} , and to the "pillow" potential, V^{pillow} , in the following way:

$$V^t = V^{IDIS} + V^{pillow} \quad (1)$$

where $V^{IDIS} = (1-S)(CNL - \Phi_M)$, and $V^{Pillow} = SV_0^{Pillow}$, S being the interface screening parameter and V_0^{Pillow} the bare "pillow" potential induced by the compression of the electron metal tails at the MO interface due to the Pauli repulsion [6].

Our calculation also provides us with a method to obtain the effective coulomb interaction, U^{eff} , associated with the injection of an electron in the molecule. This can be done by rewriting equation (1) as follows:

$$V^t = (1-S)(CNL - \Phi_M) + SV_0^{Pillow} = (1-S)(CNL - \Phi_M - V_0^{Pillow}) + V_0^{Pillow} \quad (2)$$

then, U^{eff} is calculated dividing the charge transfer induced potential, $(1-S)(CNL - \Phi_M - V_0^{Pillow})$, by the charge transfer itself:

$$U^{eff} = (1-S)(CNL - \Phi_M - V_0^{Pillow}) / \delta q \equiv \delta V^{charge} / \delta q \quad (3).$$

A similar equation for the LUMO and HOMO levels has also been found recently by Louie et al [7]. We have calculated the transport gap, as discussed in references [7,8]; this gap is the LDA-energy gap plus U^{eff} ; this yields for cases A, B and C, $E_{gap}^{trans} = 3.5$ eV(A); 3.1 eV(B) and 3.1 eV(C). It should be mentioned that the calculated DOS has been obtained using a scissor operator that fit the C_{60} -energy gap [2] to the values just mentioned.

Results for the case of a tip/ C_{60} /surface geometry will be also shown and compared with the previous geometries

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Figures:

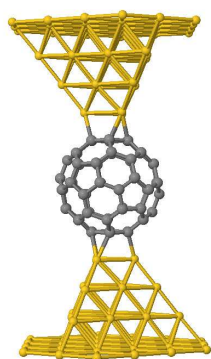


Fig. 1. Geometry of the C_{60} molecule between the gold tips